



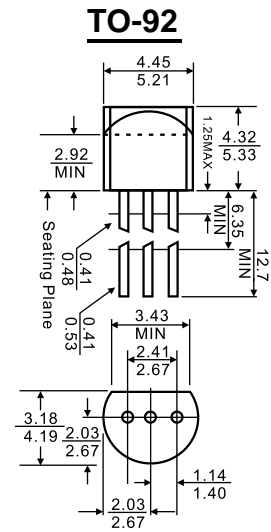
1. COLLECTOR
2. BASE
3. EMITTER

## Features

- ✧ Amplifier dissipation NPN Silicon

### MAXIMUM RATINGS (T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage BC237	45	V
	BC238/239	25	
V <sub>EBO</sub>	Emitter-Base Voltage BC237	6	V
	BC238/239	5	
I <sub>C</sub>	Collector Current -Continuous	0.1	A
P <sub>C</sub>	Collector Power Dissipation	350	mW
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	357	°C/W
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	125	°C/W
T <sub>j</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55-150	°C



Dimensions in inches and (millimeters)



### ELECTRICAL CHARACTERISTICS (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=100\mu A, I_E=0$ BC237	50			V
		BC238/239	30			
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=2mA, I_B=0$ BC237	45			V
		BC238/239	25			
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=100\mu A, I_C=0$ BC237 BC238/239	6 5			V
Collector cut-off current	$I_{CBO}$	$V_{CE}=50V, V_{BE}=0$ BC237 $V_{CB}=30V, I_E=0$ BC238/239			15	nA
DC current gain	$h_{FE(1)}$	$V_{CE}=5V, I_C=10\mu A$ BC237A		90		
		BC237B/238B		150		
		BC237C/238C/239C		270		
	$h_{FE(2)}$	$V_{CE}=5V, I_C=2mA$ BC237	120		800	
		BC239	120		800	
		BC237A	120		220	
		BC237B/238B	200		460	
		BC237C/238C/239C	380		800	
	$h_{FE(3)}$	$V_{CE}=5V, I_C=100mA$ BC237A		120		
		BC237B/238B		180		
		BC237C/238C/239C		300		
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=10mA, I_B=0.5mA$ BC237/238/239			0.2	
		$I_C=100mA, I_B=5mA$ BC237/239			0.6	V
		BC238			0.8	
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=10mA, I_B=0.5mA$			0.83	V
		$I_C=100mA, I_B=5mA$			1.05	
Base-emitter voltage	$V_{BE}$	$V_{CE}=5V, I_C=0.1mA$		0.5		
		$V_{CE}=5V, I_C=2mA$	0.55		0.7	V
		$V_{CE}=5V, I_C=100mA$		0.83		
Transition frequency	$f_T$	$V_{CE}=3V, I_C=0.5mA, f=100MHz$ BC237		100		
		BC238		120		
		BC239		140		
		$V_{CE}=5V, I_C=10mA, f=100MHz$ BC237	150	200		MHz
		BC238	150	240		
BC239	150	280				
Collector output capacitance	$C_{ob}$	$V_{CB}=10V, I_E=0, f=1MHz$			4.5	pF
Emitter-base capacitance	$C_{ib}$	$V_{EB}=0.5V, I_C=0, f=1MHz$		8		Pf
Noise figure	NF	$V_{CE}=5V, I_C=0.2mA,$ $f=1kHz, R_s=2K\Omega$ BC239		2	4	
		$V_{CE}=5V, I_C=0.2mA,$ $f=1kHz, R_s=2K\Omega, \Delta f=200Hz$ BC237		2	10	dB
		BC238		2	10	
		BC239		2	4	



## Typical Characteristics

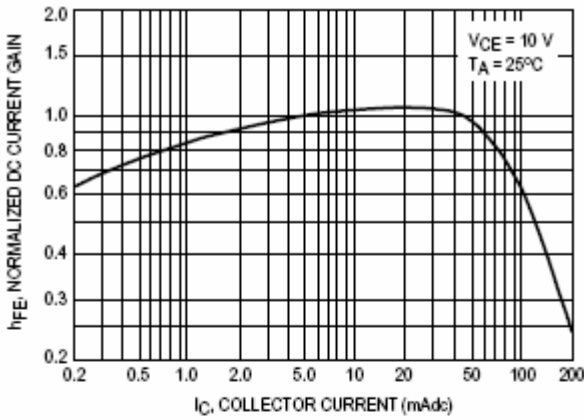


Figure 1. Normalized DC Current Gain

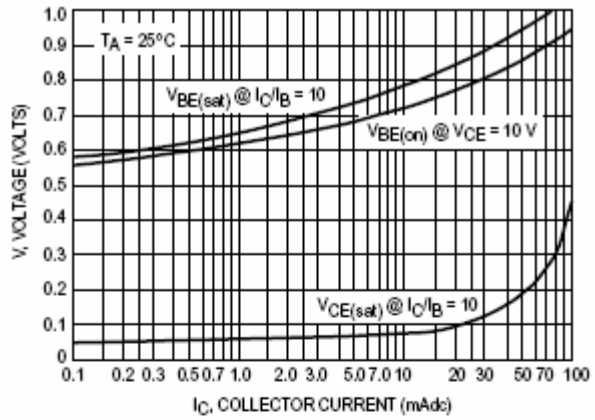


Figure 2. "Saturation" and "On" Voltages

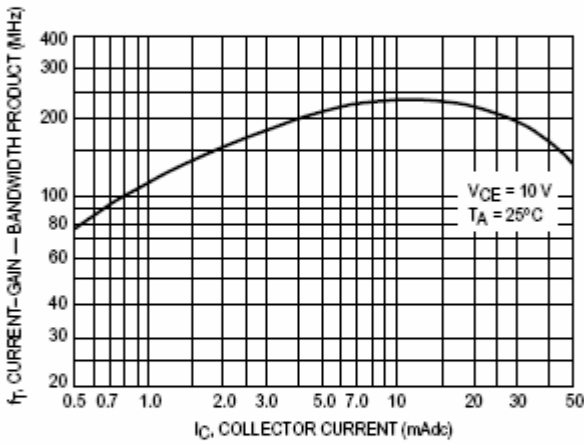


Figure 3. Current-Gain — Bandwidth Product

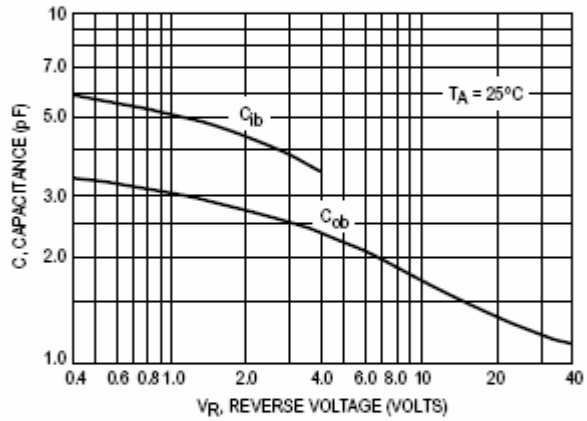


Figure 4. Capacitances

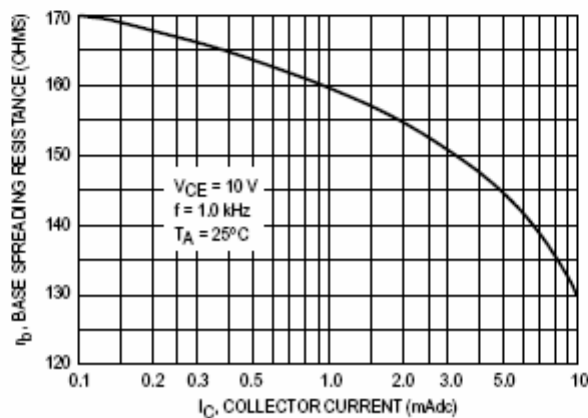


Figure 5. Base Spreading Resistance

Package	Packing	Quantity	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	Bulk	1000pcs/BP	10,000pcs	245×170×100	100,000pcs	525×375×270
TO-92	Tape	2000pcs/TP	2000pcs	333×162×43	20,000pcs	350×340×250